

## MS1263

### RF & MICROWAVE TRANSISTOR UHF MOBILE APPLICATIONS

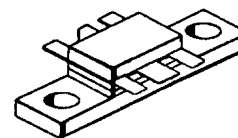
#### Features

- 512 MHz
- 12.5 VOLTS
- $P_{OUT} = 15\text{ W MINIMUM}$
- $G_p = 7.8\text{ dB}$
- INPUT MATCHED
- COMMON EMITTER CONFIGURATION

#### DESCRIPTION:

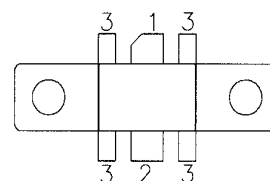
The MS1263 is a NPN silicon RF power transistor designed for 12.5-volt UHF amplifier applications operating to 512 MHz. The MS1263 has internal impedance matching for broadband operation and diffused emitter ballast for high load VSWR tolerance.

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**.230 6LFL (M142)**  
epoxy sealed

#### PIN CONNECTION



1. Collector      3. Base  
2. Emitter

#### ABSOLUTE MAXIMUM RATINGS ( $T_{case} = 25^{\circ}\text{C}$ )

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	36	V
$V_{CEO}$	Collector-Emitter Voltage	16	V
$V_{EBO}$	Emitter-Base Voltage	4.0	V
$I_C$	Collector Current	3.4	A
$P_{TOT}$	Total Power Dissipation	37.5	W
$T_{STG}$	Storage Temperature	-65 to +150	$^{\circ}\text{C}$
$T_J$	Junction Temperature	+200	$^{\circ}\text{C}$

#### Thermal Data

$R_{\theta JC}$	Thermal Resistance Junction-case	4.6	$^{\circ}\text{C/W}$
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**ELECTRICAL SPECIFICATIONS (T<sub>case</sub> = 25°C)**
**STATIC**

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
<b>BV<sub>CEO</sub></b>	<b>I<sub>C</sub> = 50mA      I<sub>B</sub> = 0</b>	<b>16</b>	---	---	<b>V</b>
<b>BV<sub>CES</sub></b>	<b>I<sub>C</sub> = 50mA      V<sub>BE</sub> = 0</b>	<b>36</b>	---	---	<b>V</b>
<b>BV<sub>EBO</sub></b>	<b>I<sub>E</sub> = 5.0mA      I<sub>C</sub> = 0</b>	<b>4.0</b>	---	---	<b>V</b>
<b>I<sub>CES</sub></b>	<b>V<sub>CE</sub> = 15V      V<sub>BE</sub> = 0</b>	---	---	<b>5.0</b>	<b>mA</b>
<b>H<sub>FE</sub></b>	<b>V<sub>CE</sub> = 5.0V      I<sub>C</sub> = 500mA</b>	<b>20</b>	---	<b>120</b>	---

**DYNAMIC**

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
<b>P<sub>OUT</sub></b>	<b>f = 512 MHz      P<sub>IN</sub> = 2.5 W      V<sub>CC</sub> = 12.5V</b>	<b>15</b>	---	---	<b>W</b>
<b>G<sub>P</sub></b>	<b>f = 512 MHz      P<sub>IN</sub> = 2.5 W      V<sub>CC</sub> = 12.5V</b>	<b>7.8</b>	---	---	<b>dB</b>
<b>η<sub>c</sub></b>	<b>f = 512 MHz      P<sub>IN</sub> = 2.5 W      V<sub>CC</sub> = 12.5V</b>	<b>50</b>	---	---	<b>%</b>
<b>C<sub>OB</sub></b>	<b>f = 1.0 MHz      V<sub>CB</sub> = 12.5V</b>	---	---	<b>50</b>	<b>pf</b>

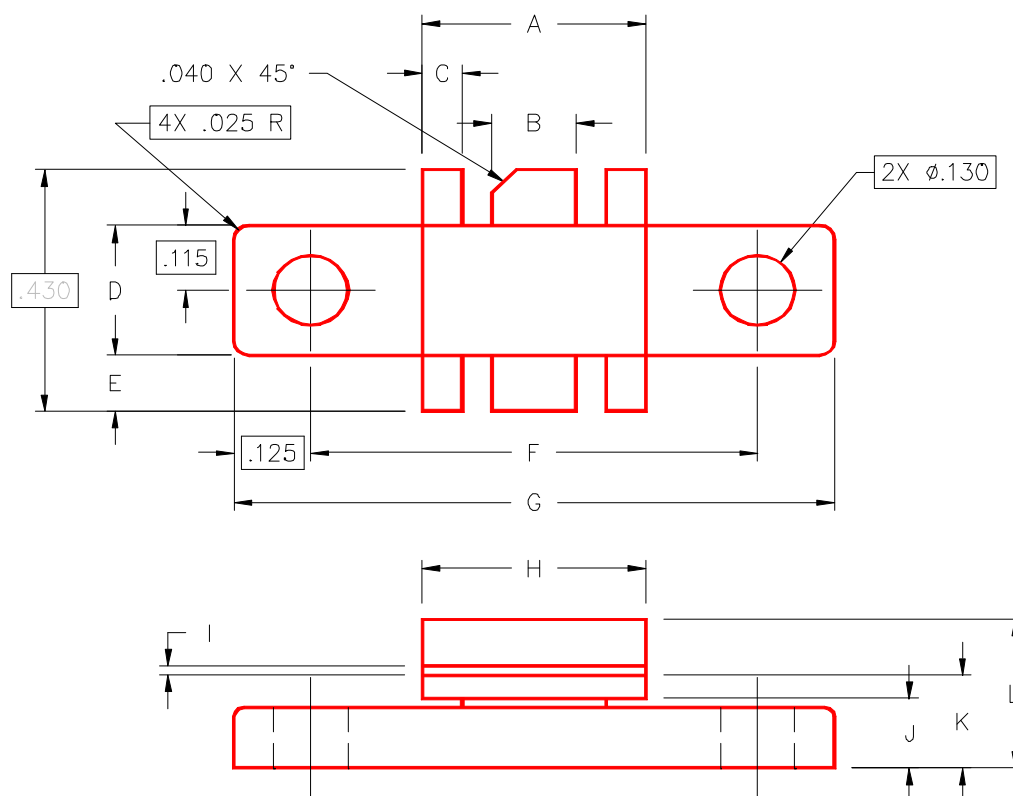
**IMPEDANCE DATA**

FREQ	Z <sub>IN</sub> (Ω)	Z <sub>CL</sub> (Ω)
<b>470 MHz</b>	<b>0.95 – j1.1</b>	<b>2.2 + j0.9</b>
<b>512 MHz</b>	<b>0.82 + j2.5</b>	<b>2.1 + j2.3</b>

**P<sub>IN</sub>=2.5W**  
**V<sub>CE</sub>=12.5V**

## PACKAGE MECHANICAL DATA

### PACKAGE STYLE M142



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.355/9,02	.365/9,27	I	.004/0,10	.006/0,15
B	.115/2,92	.125/3,18	J	.120/3,05	.130/3,30
C	.075/1,91	.085/2,16	K	.160/4,06	.180/4,57
D	.225/5,72	.235/5,97	L	.230/5,84	.260/6,60
E	.090/2,29	.110/2,79			
F	.720/18,29	.730/18,54			
G	.970/24,64	.980/24,89			
H	.355/9,02	.365/9,27			